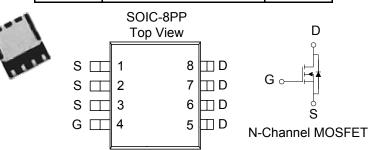
N-Channel 60-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

•	Low r _{DS(on)} provides higher efficiency and
	extends battery life

- Low thermal impedance copper leadframe SOIC-8PP saves board space
- Fast switching speed
- High performance trench technology

PRODUCT SUMWARY				
$V_{DS}(V)$	$r_{DS(on)} m(\Omega)$	$I_{D}(A)$		
60	$82@V_{CS} = 10V$	6.4		
	$115 @V_{CS} = 4.5V$	5.4		



ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED)					
Parameter		Symbol	Maximum	Units	
Drain-Source Voltage			60	V	
Gate-Source Voltage		V_{cs}	20	V	
Continuous Drain Current ^a	T _A =25°C	Τ	6.4		
Continuous Drain Current	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	ц	5.3	A	
Pulsed Drain Current ^b	·	I_{DM}	20		
Continuous Source Current (Diode Conduction) ^a		I_S	2.3	Α	
D a	$T_A=25^{\circ}C$	D	5.0	W	
Power Dissipation ^a	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	LD	3.2	VV	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to 150	°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Maximum	Units	
	$t \le 10 \sec$	D	25	°C/W	
Maximum Junction-to-Ambient ^a	Steady State	$R_{\theta JA}$	65	°C/W	

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Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

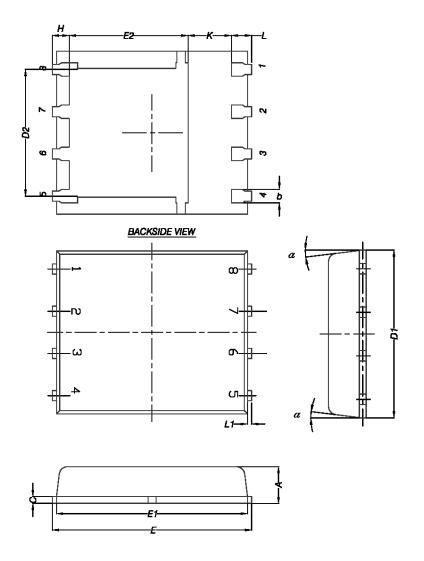
SPECIFICATIONS (T _A =25°C UNLESS OTHERWISE NOTED)							
Parameter	Gradad	Total Constitutions	Limits			T Laid	
raianeter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static	•		•			*	
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_D=250$ uA	1			V	
Gate-Body Leakage	IGSS	$V_{DS} = 0 \text{ V}, V_{GS} = 12 \text{ V}$			100	nA	
Zara Cata Valtaga Drain Gurrant	Ingg	V_{DS} =48 V, V_{GS} =0 V			1	uA	
Zero Gate Voltage Drain Current	IDSS	V_{DS} =48 V, V_{CS} =0 V, T_J =55°C			5	uA	
On-State Drain Current ^A	I _{D(on)}	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	40			Α	
D : G . D : A		$V_{GS} = 10 \text{ V}, I_D = 2 \text{ A}$			82	mΩ	
Drain-Source On-Resistance ^A	TDS(on)	$V_{GS} = 4.5 \text{ V, } I_D = 2 \text{ A}$			115	111.2	
Forward Tranconductance ^A	gs	$V_{DS} = 15 \text{ V}, I_D = 6 \text{ A}$		40		S	
Diode Forward Voltage	Vsd	$I_S = 2.3 A, V_{GS} = 0 V$		0.7		V	
Dynamic ^b							
Total Gate Charge	Qg	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V},$		15			
Gate-Source Charge	Qgs	VDS - 13 V, VGS - 4.3 V, In=6A		3		пC	
Gate-Drain Charge	Qgd	Б-6 А		5			
Turn-On Delay Time	t _{d(on)}			15			
Rise Time	t_{r}	$V_{DD}=15 \text{ V}, R_L=6\Omega, ID=1 \text{ A},$		10		C	
Tum-Off Delay Time	td(off)	VOEN = 10 V		54		nS	
Fall-Time	tf			26			

Notes

- a. Pulse test: $PW \le 300us duty cycle \le 2\%$.
- b. Guaranteed by design, not subject to production testing.

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Package Information



	MILLIMETERS			
DIM.	MIN.	NOM.	MAX.	
Α	0.90	1.00	1.10	
b	0.33	0.41	0.51	
С	0.20	0.25	0.30	
D1	4.80	4.90	5.00	
D2	3.61	3.81	3.96	
E	5.90	6.00	6.10	
E1	5.70	5.75	5.80	
E2	3.38	3.58	3.78	
Θ	1.27 BSC			
Н	0.41	0.51	0.61	
K	1.10	-	-	
L	0.51	0.61	0.71	
L1	0.06	0.13	0.20	
α	O°	-	12°	